Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.673 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.557 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakover voltage, dc

Current Rating Per Characteristic:

35.00 amperes source cutoff current of standard range

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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